

ESD959-B1-W0201

Very high linearity bi-directional ESD protection device, 16 V, 0.11 pF, 0201

Product description

ESD protection device with a bi-directional I/V characteristic and excellent clamping performance, extremely low capacitance and high linearity for mobile device antenna.

Feature list

- ESD / transient protection according to:
 - IEC61000-4-2 (ESD): ± 20 kV (air) / ± 20 kV (contact)
 - IEC61000-4-4 (EFT): ± 1.5 kV / ± 30 A (5/50 ns)
 - IEC61000-4-5 (Surge): ± 3.5 A (8/20 μ s)
- Bi-directional maximum working voltage: $V_{WM} = \pm 16$ V
- Line capacitance: $C_L = 0.11$ pF at $f = 2.5$ GHz
- Insertion loss: $IL = 0.12$ dB at $f = 2.5$ GHz
- Very low harmonics: $P_{H3} = -81$ dBm at Pin = 10 dBm and $f = 0.9$ GHz
- Clamping voltage: $V_{cl} = 34.7$ V at $I_{TLP} = 16$ A with $R_{dyn} = 0.7 \Omega$
- Very low leakage current: $I_L = 1$ nA
- Small form factor SMD size 0201, low profile (0.58 x 0.28 x 0.15 mm³)



Potential applications

- RF antennas and interfaces (LTE, WLAN)

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Device information

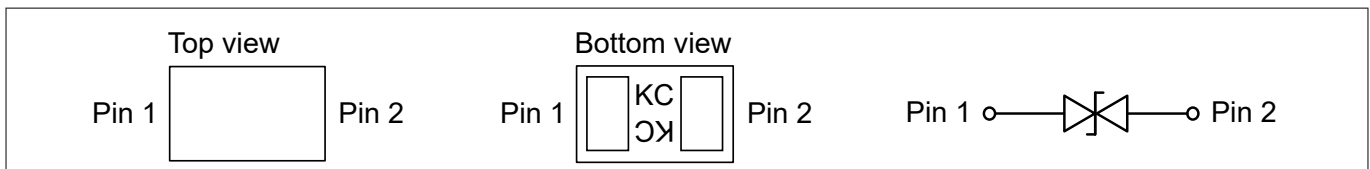


Figure 1 Pin configuration and schematic diagram

Table 1 Part information

Product name / Ordering code	Package	Pin configuration	Marking	Pieces / Reel
ESD959-B1-W0201 / ESD959B1W0201E6327XTSA1	WLL-2-3	1 line, bi-directional	KC	15 k



Table of contents

	Product description	1
	Feature list	1
	Potential applications	1
	Product validation	1
	Device information	1
	Table of contents	2
1	Absolute maximum ratings	3
2	Electrical characteristics	4
3	Typical characteristic diagrams	6
4	Package information WLL-2-3	13
	References	14
5	Revision history	14
	Disclaimer	15

1 Absolute maximum ratings

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Table 2 Absolute maximum ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values		Unit	Note or test condition
		Min.	Max.		
Working voltage	V_{WM}	-16	+16	V	
ESD discharge voltage	V_{ESD} (contact)	-20	+20	kV	Discharge network: $R = 330 \Omega$, $C = 150 \text{ pF}$ ¹⁾
	V_{ESD} (air)	-20	+20		
Peak pulse power	P_{PK}	-	95	W	Stress pulse: 8/20 μs current waveform ²⁾
Peak pulse current	I_{PP}	-3.5	+3.5	A	
Operating temperature	T_{op}	-55	+125	°C	
Storage temperature	T_{stg}	-55	+150		

Attention: *Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.*

¹⁾ Based on IEC61000-4-2.

²⁾ Based on IEC61000-4-5.

2 Electrical characteristics

2 Electrical characteristics

Note: $T_A = 25^\circ\text{C}$, unless otherwise specified. Device is electrically symmetrical.

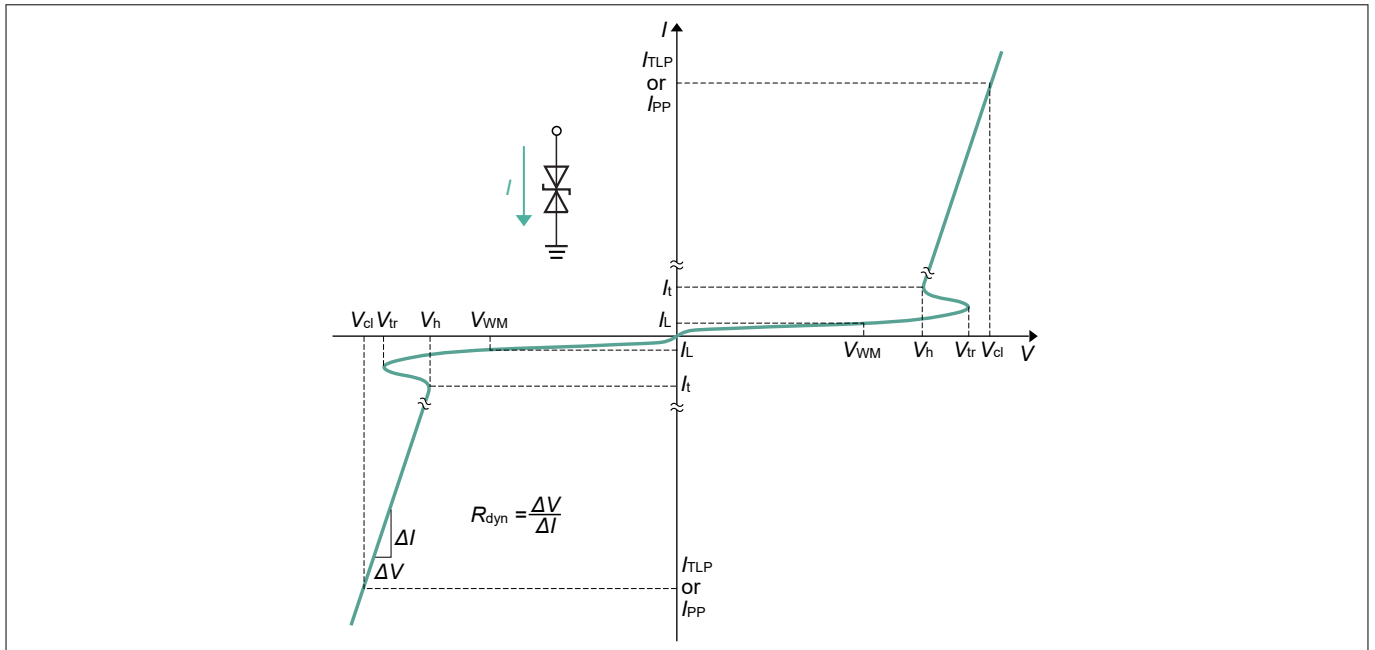


Figure 2 I/V characteristic curve

Table 3 I/V characteristic parameters

Symbol	Parameter
I_h	Holding current
I_L	Leakage current
I_{PP}	Peak pulse current, based on IEC61000-4-5
I_t	Test current
I_{TLP}	TLP current
R_{dyn}	Dynamic resistance
V_{cl}	Clamping voltage
V_h	Holding voltage
V_t	Test voltage
V_{tr}	Trigger voltage
V_{WM}	Maximum working voltage

Note: For more detailed explanation of electrical parameters, refer to [1].

2 Electrical characteristics

Table 4 DC characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Trigger voltage	V_{tr}	–	26	–	V	
Holding voltage	V_h	17	20	–		$I_h = 10 \text{ mA}$
Leakage current	I_L	–	<0.1	50	nA	$V_{WM} = 16 \text{ V}$

Table 5 AC characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	0.21	0.4	pF	$V = 0 \text{ V}, f = 1 \text{ MHz}$
		–	0.11	–		$V = 0 \text{ V}, f = 2.5 \text{ GHz}$
Series inductance	L_S	–	<0.1	–	nH	Extracted from S-parameters

Table 6 Protection characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Clamping voltage (TLP) ^{3) 4)}	V_{cl}	–	26.3	–	V	$I_{TLP} = 4 \text{ A}$
		–	29.3	–		$I_{TLP} = 8 \text{ A}$
		–	34.7	–		$I_{TLP} = 16 \text{ A}$
		–	44.9	–		$I_{TLP} = 30 \text{ A}$
Clamping voltage (8/20 μs) ⁵⁾		–	22.5	–		$I_{PP} = 1 \text{ A}$
		–	24.4	–		$I_{PP} = 2 \text{ A}$
		–	26.3	–		$I_{PP} = 3 \text{ A}$
		–	27.2	–		$I_{PP} = 3.5 \text{ A}$
Dynamic resistance ³⁾	R_{dyn}	–	0.7	–	Ω	

³⁾ TLP parameters: $Z_0 = 50 \Omega$, $t_p = 100 \text{ ns}$, $t_r = 0.6 \text{ ns}$, averaging window 30-60 ns.

⁴⁾ Refer to application note [2].

⁵⁾ $t_p = 8/20 \mu\text{s}$. Stress pulse based on IEC61000-4-5.

3 Typical characteristic diagrams

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Note: $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified.

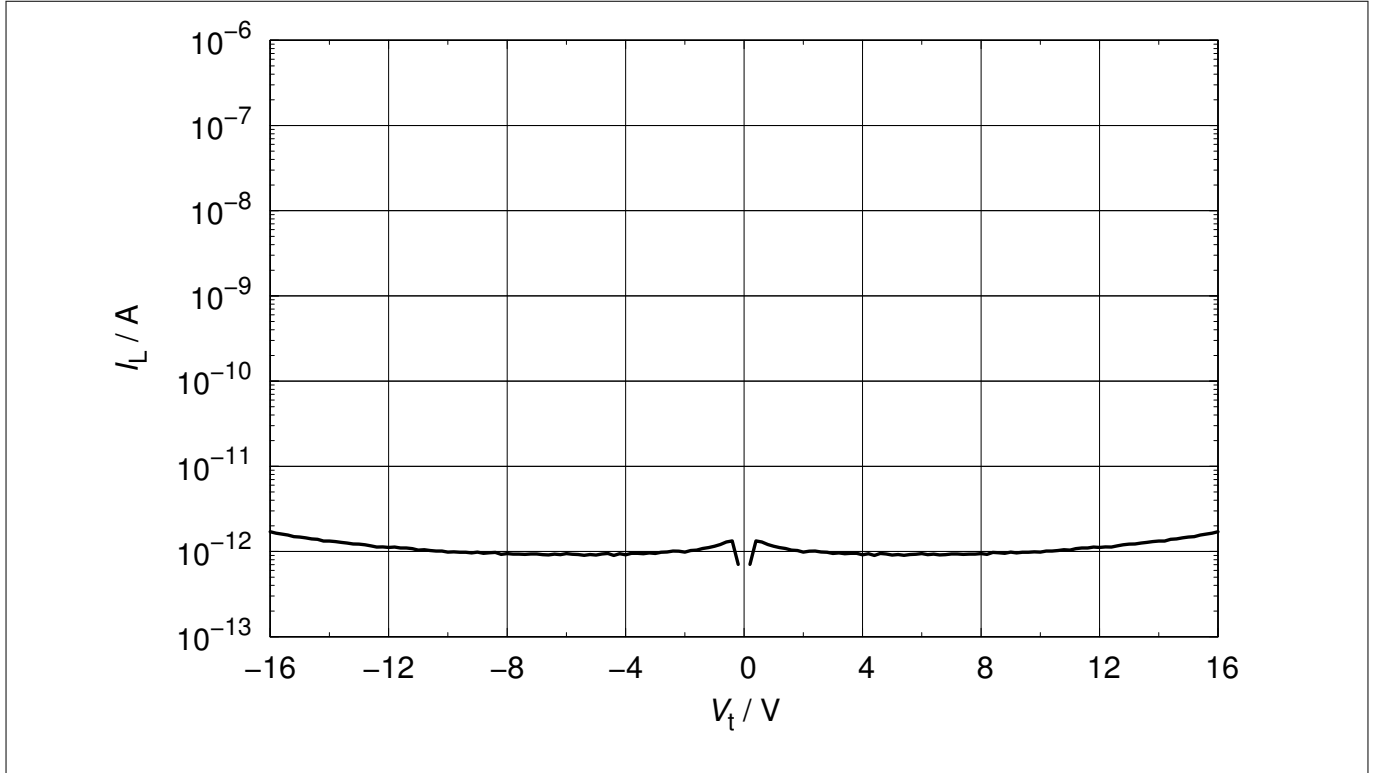


Figure 3 Leakage current: $I_L = f(V_t)$

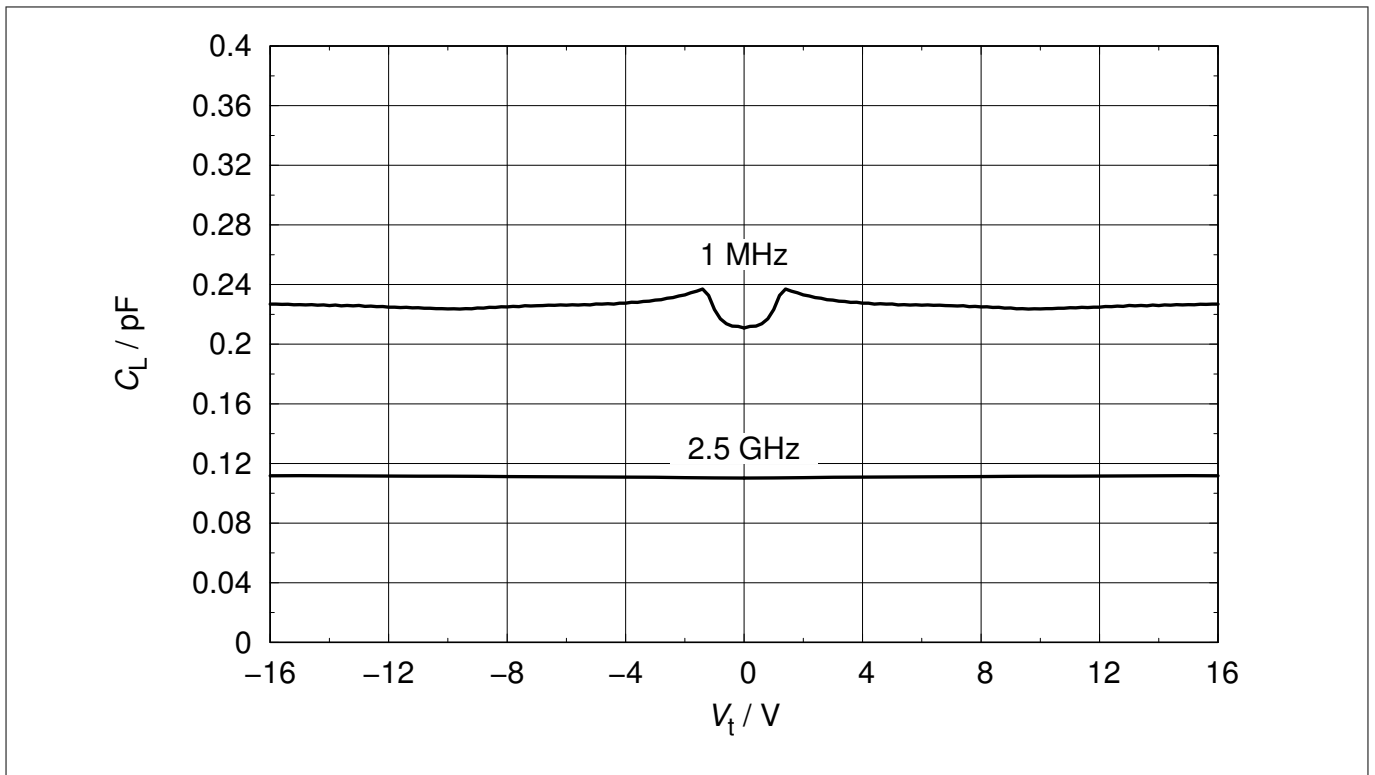


Figure 4 Line capacitance: $C_L = f(V_t)$, $f = 1\text{ MHz}$ and 2.5 GHz

3 Typical characteristic diagrams

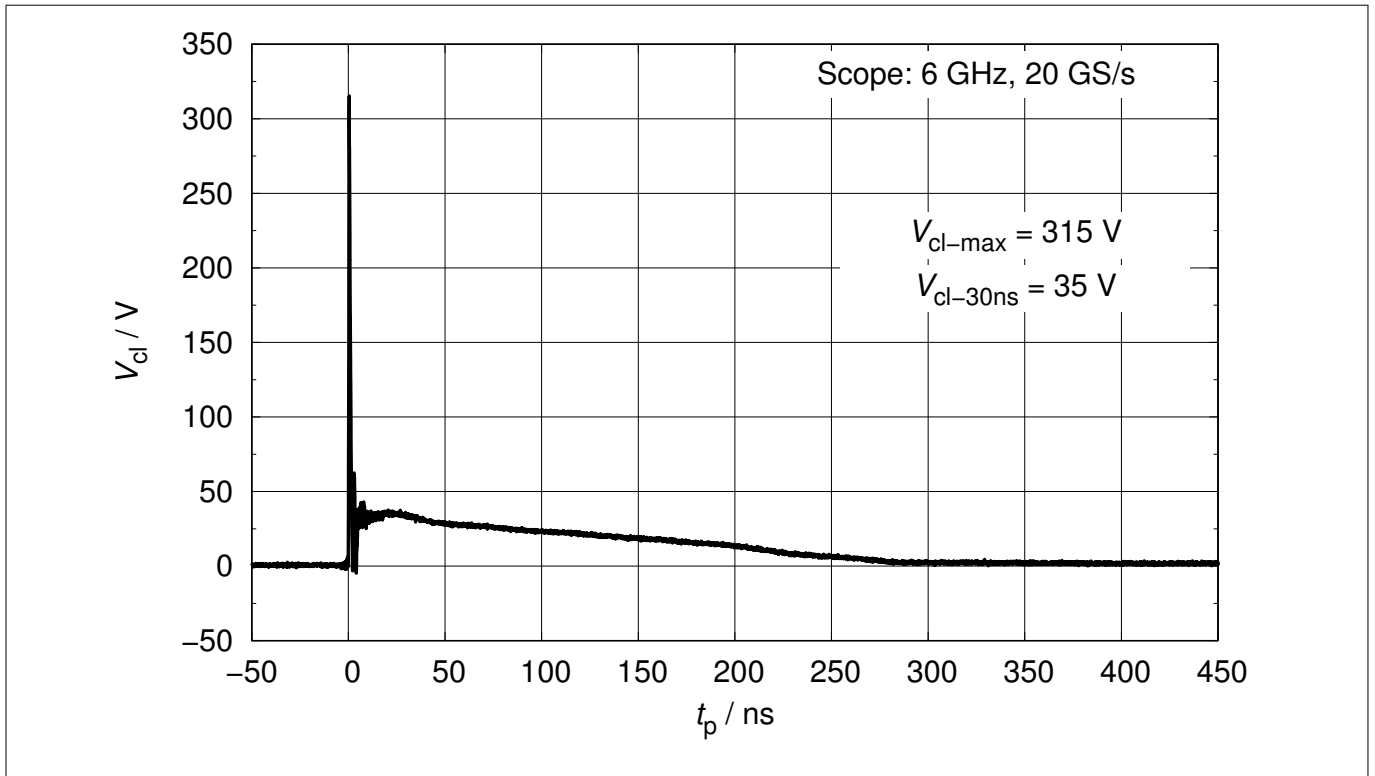


Figure 5 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV positive pulse based on IEC61000-4-2

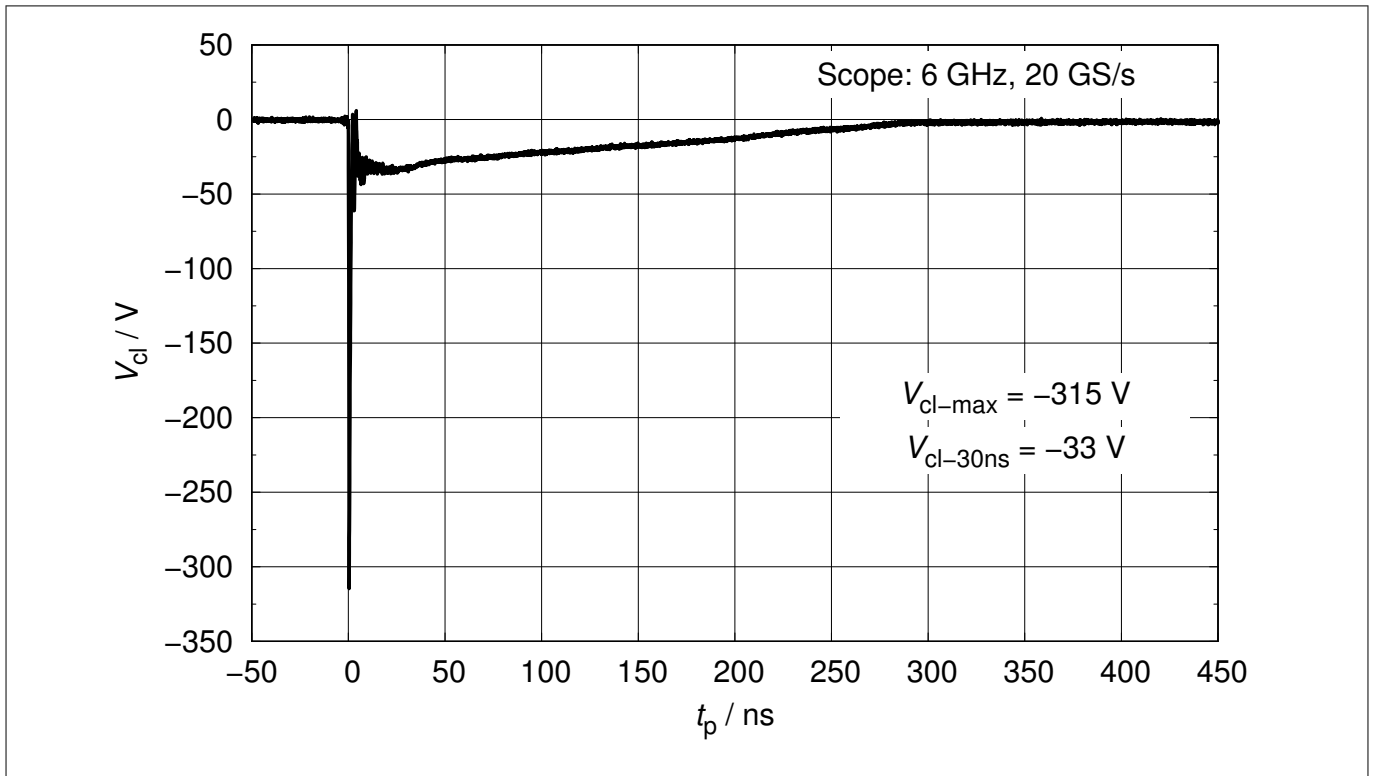


Figure 6 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV negative pulse based on IEC61000-4-2

3 Typical characteristic diagrams

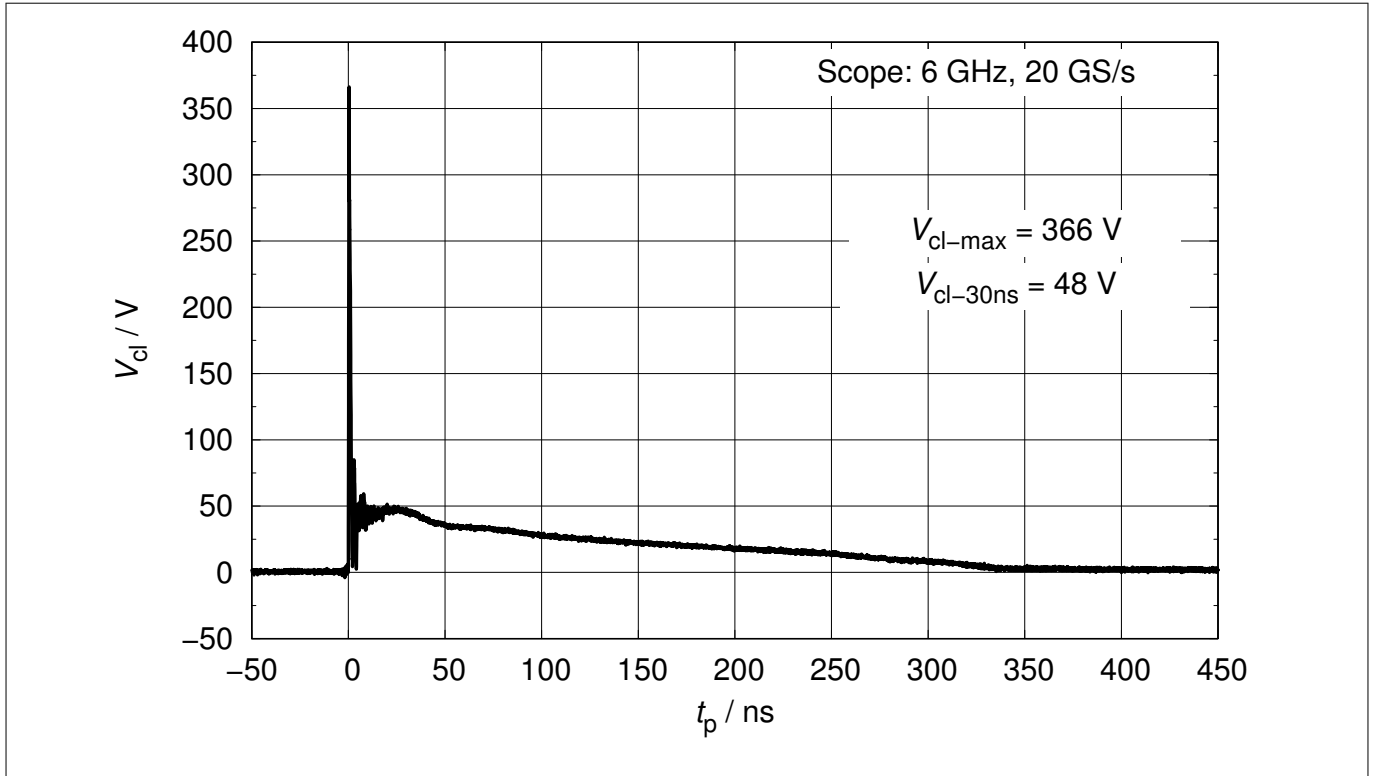


Figure 7 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 15 kV positive pulse based on IEC61000-4-2

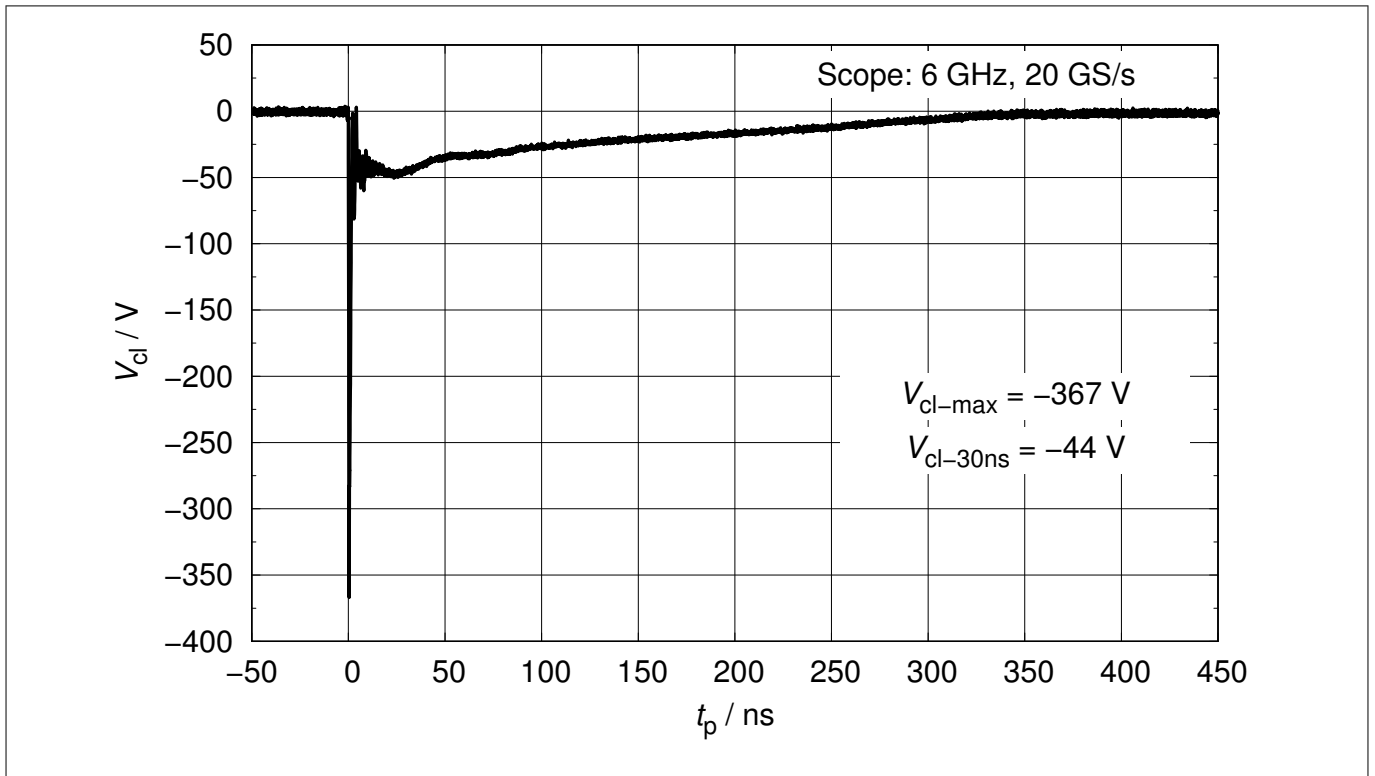


Figure 8 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 15 kV negative pulse based on IEC61000-4-2

3 Typical characteristic diagrams

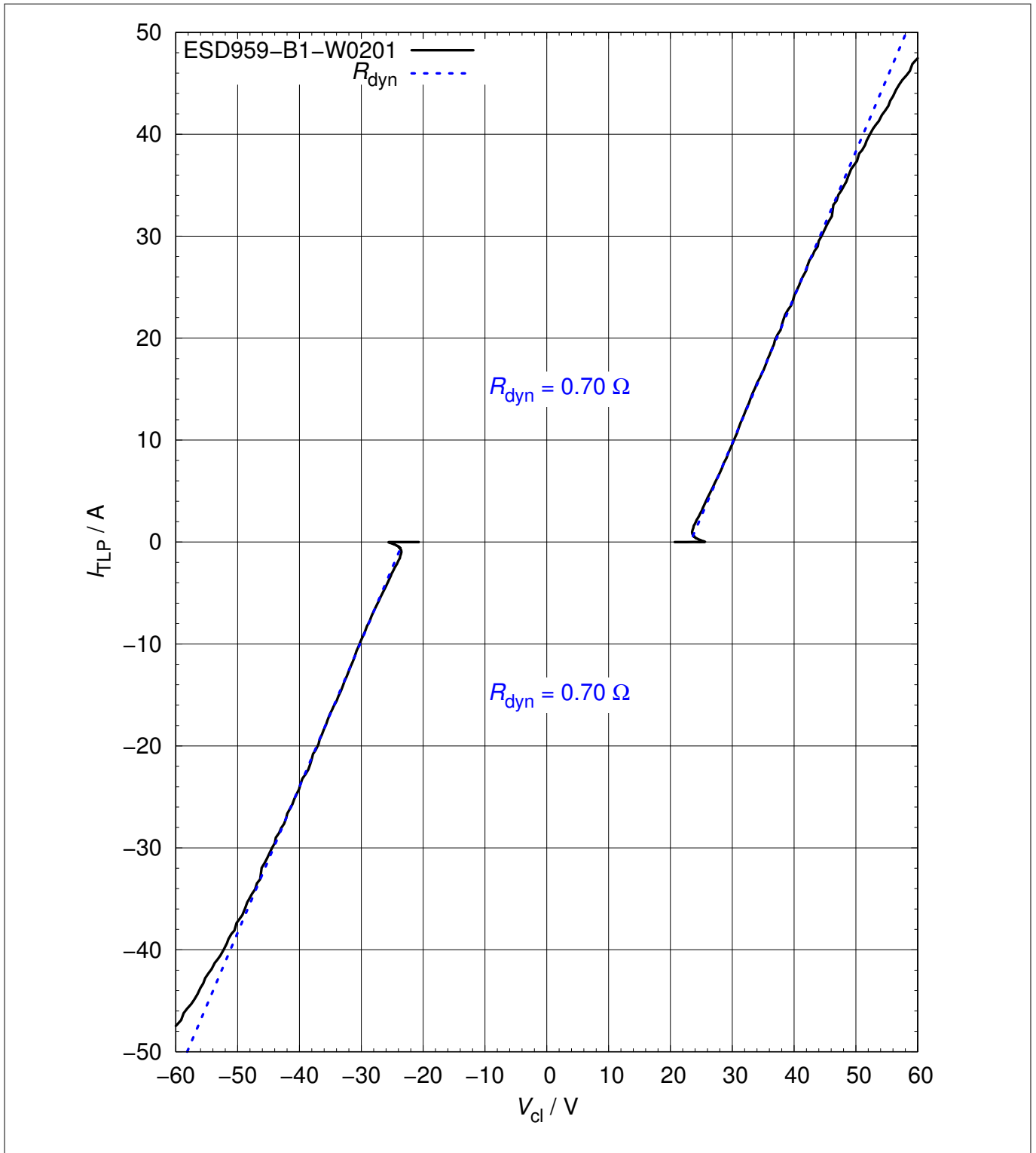


Figure 9 Clamping voltage (TLP): $I_{TLP} = f(V_{cl})$

3 Typical characteristic diagrams

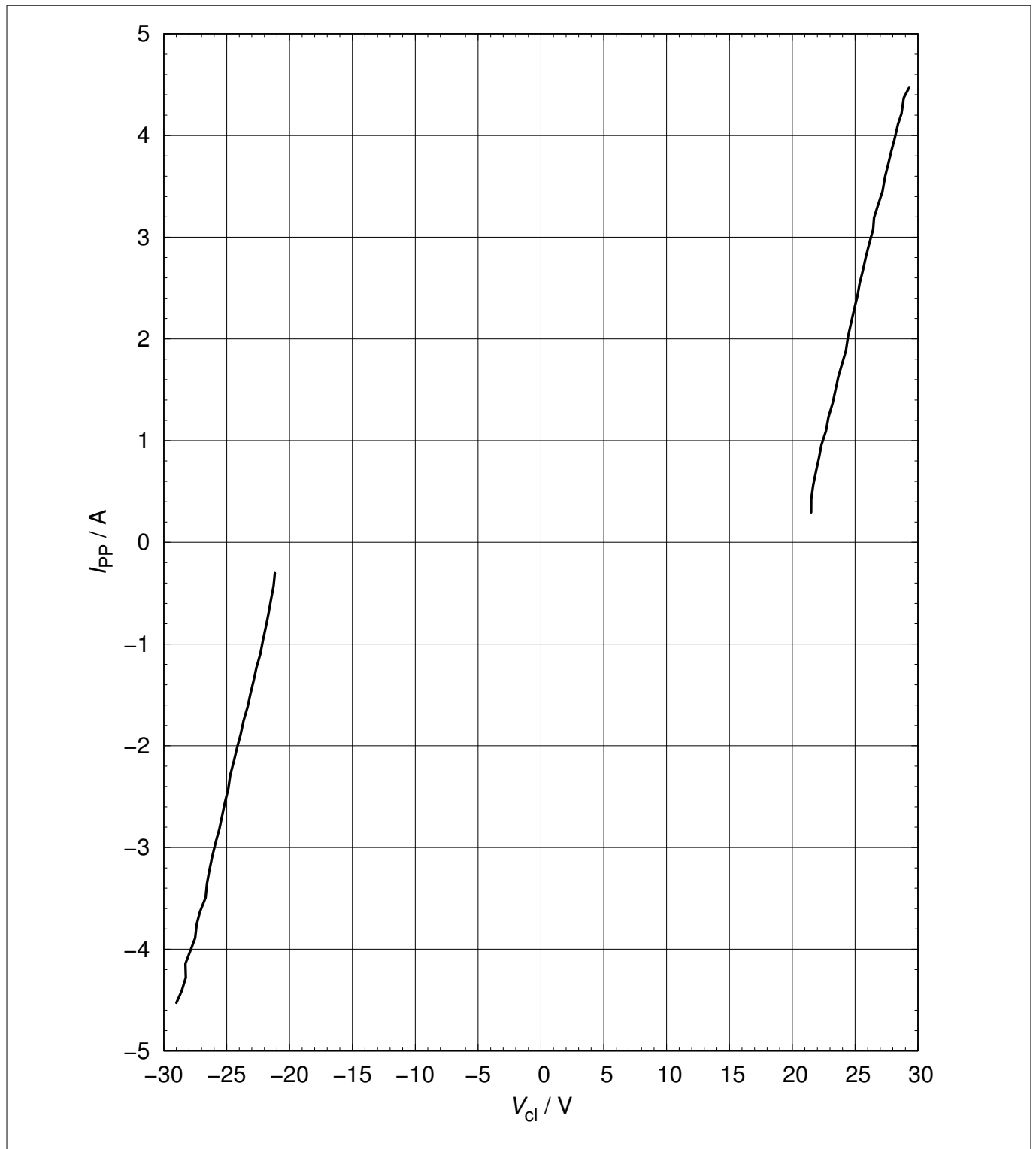


Figure 10 Clamping voltage (Surge): $I_{PP} = f(V_{Cl})$, based on IEC61000-4-5

3 Typical characteristic diagrams

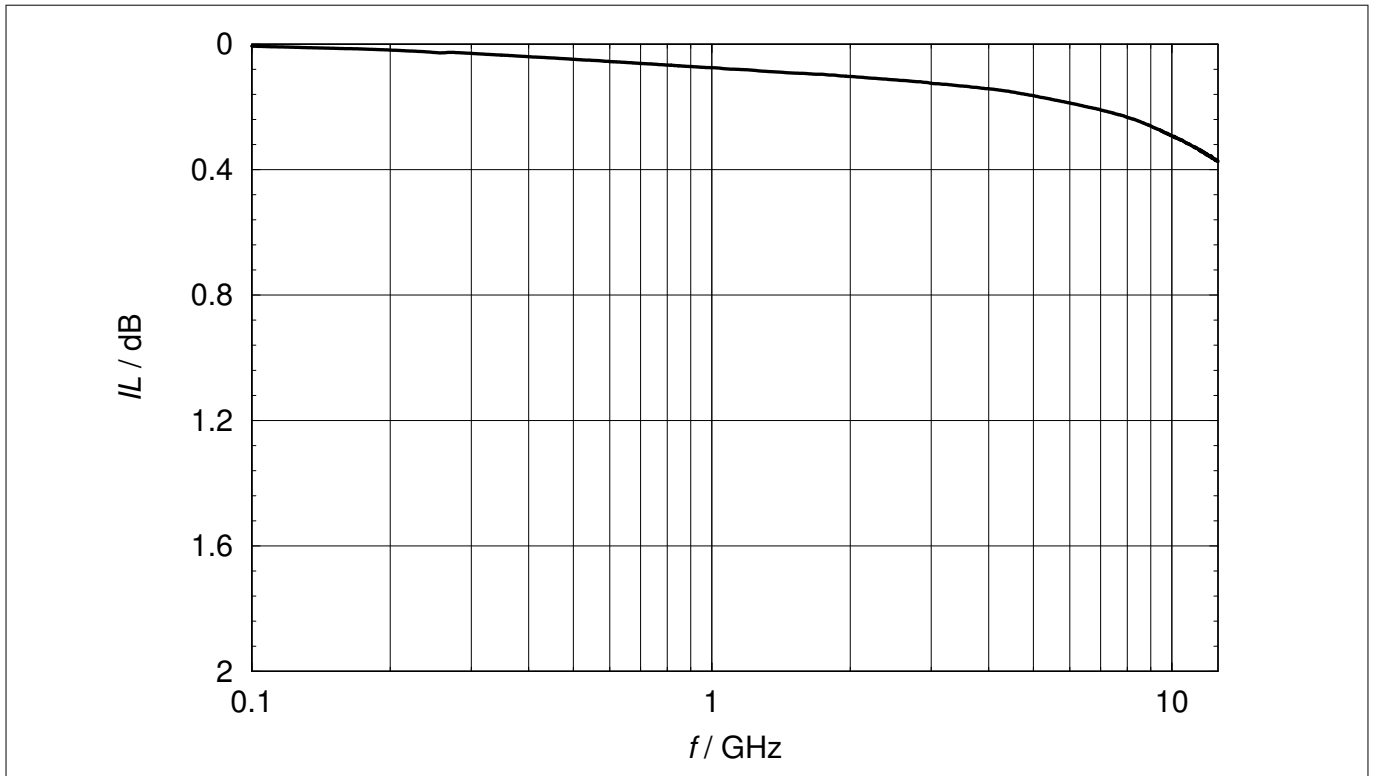


Figure 11 Insertion loss $IL = f(f)$, measured in a 50 Ω system

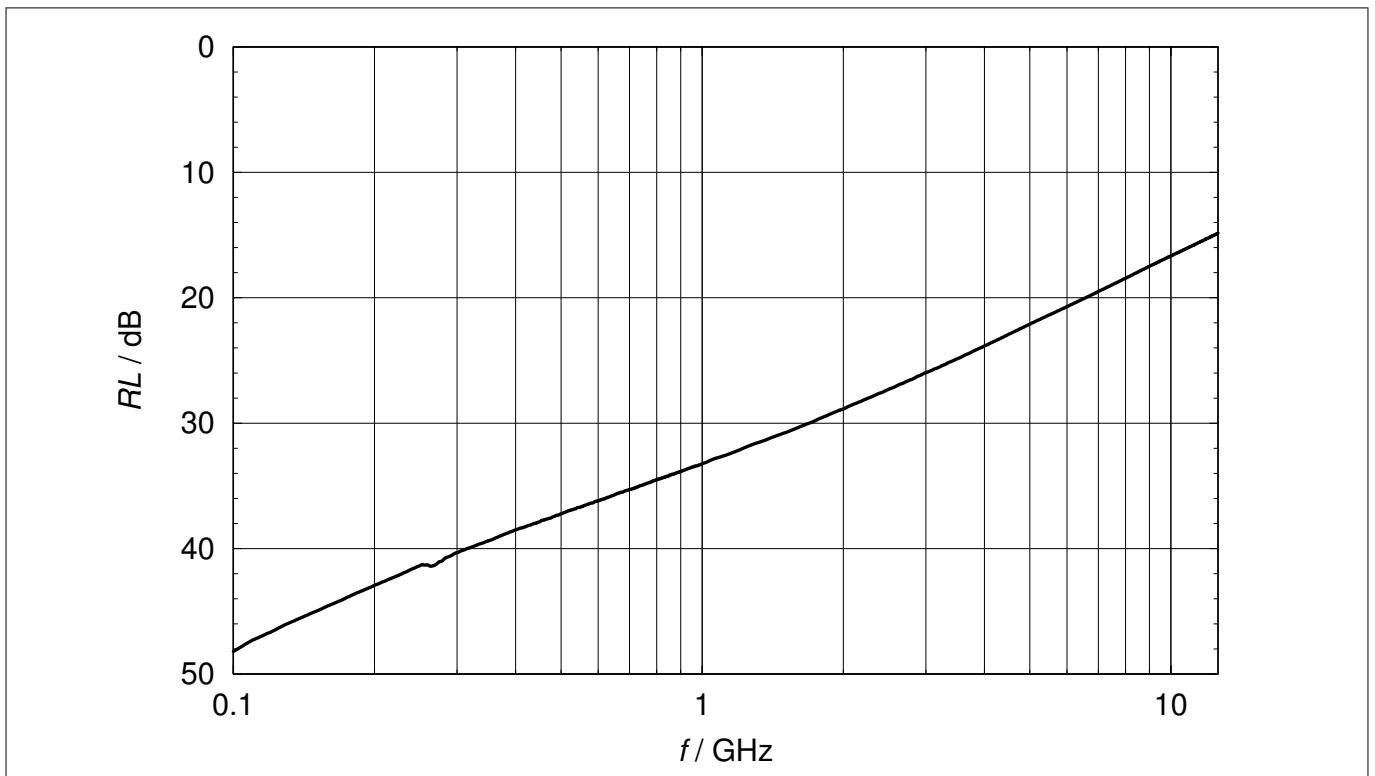


Figure 12 Return loss $RL = f(f)$, measured in a 50 Ω system

3 Typical characteristic diagrams

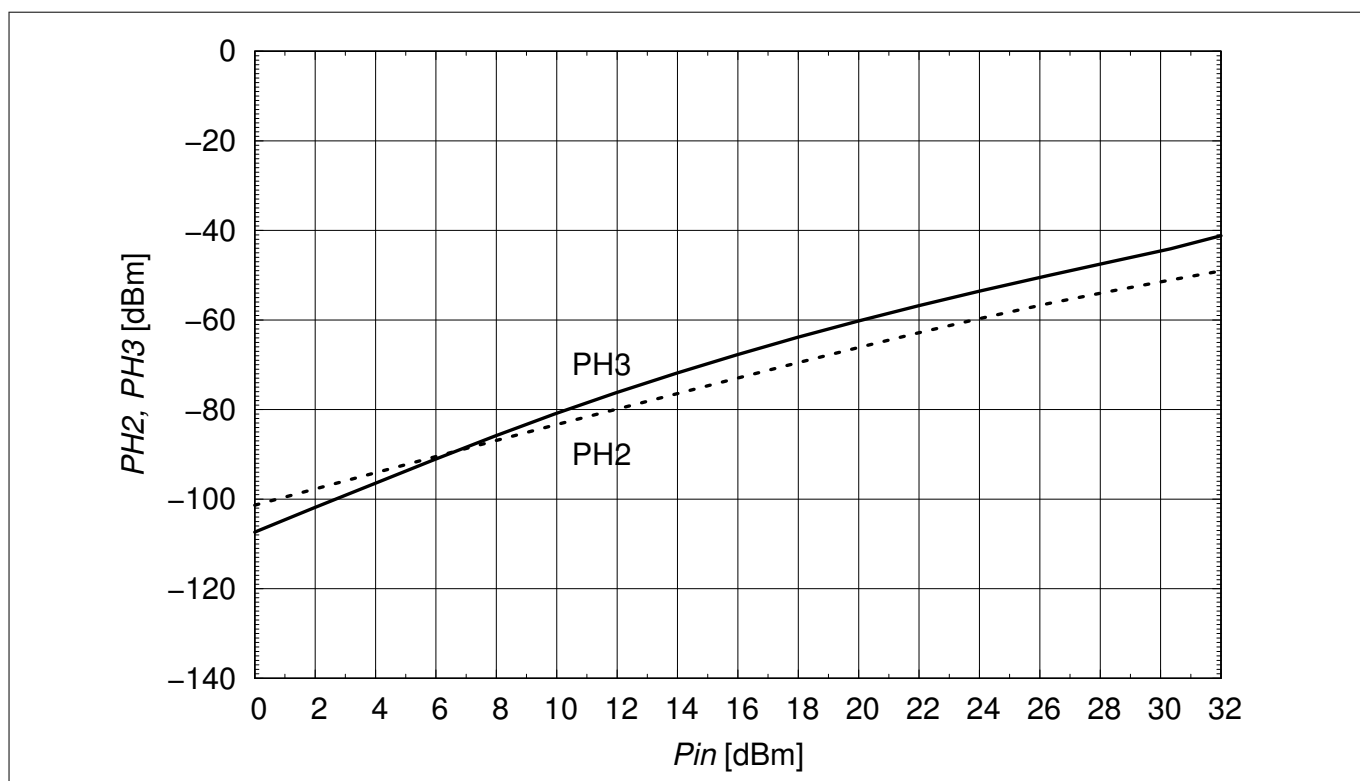


Figure 13 Second and third harmonic power: $P_{H2}, P_{H3} = f(P_{in})$ at $f = 900$ MHz

4 Package information WLL-2-3

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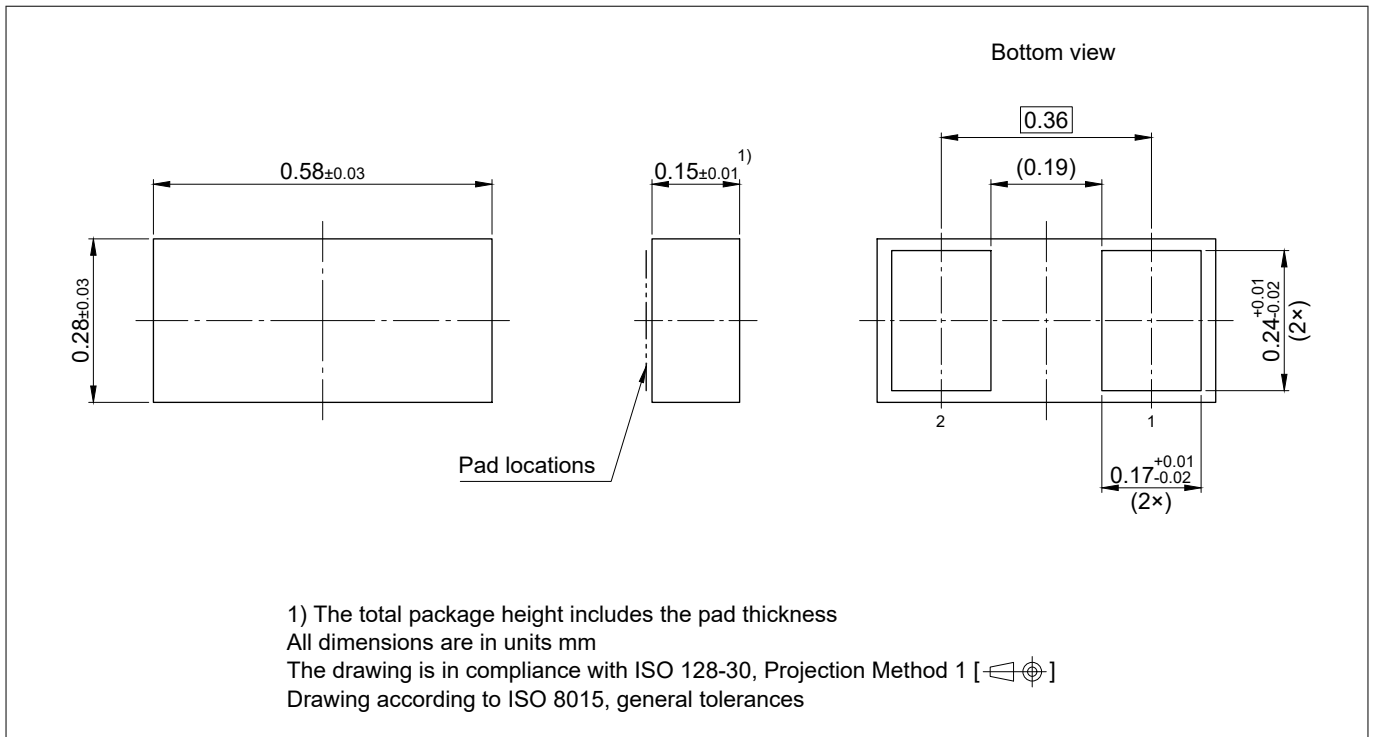


Figure 14 WLL-2-3 package

Note: For package information including footprint, packing and assembly recommendation refer to:

<https://www.infineon.com/package/SG-WLL-2-3/>

References**References**

- [1] Infineon Technologies AG: *Understanding ESD protection device characteristics product information*; [Available online](#)
- [2] Infineon Technologies AG: *Effective ESD protection design at system level using VF-TLP characterization methodology application note*; [Available online](#)

5 Revision history

Document version	Date of release	Description of changes
1.0	2024-08-30	Initial release
1.1	2026-03-13	Updated new package drawing

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